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## Colloidal quantum dot field-effect transistors

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*Document Version*

Publisher's PDF, also known as Version of record

*Publication date:*

2019

[Link to publication in University of Groningen/UMCG research database](#)

*Citation for published version (APA):*

Shulga, A. G. (2019). *Colloidal quantum dot field-effect transistors: From electronic circuits to light emission and detection*. University of Groningen.

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# Curriculum Vitae

## **Studies**

2010: BCs. in Applied Physics, Radio-physics department, National University of Kiev, Ukraine

2013: MSc. “Top master in nanoscience”, University of Groningen, Netherlands

## **Professional experience**

2011: Research engineer, Ukrainian Radiation Protection Institute, Kiev, Ukraine.

## **International conference talks:**

2017, April 17-21: MRS spring meeting 2017, Phoenix, AZ, USA. Oral presentation: “An all-solution-based high-gain hybrid CMOS-like quantum dot/carbon nanotube inverter”.

2017, January 17-18: – Physics@FOM Veldhoven, Veldhoven, The Netherlands. Oral presentation: “An all-solution-based hybrid quantum dot/carbon nanotube inverter”

2015, April 6-10: – MRS spring meeting 2015, San Francisco, USA. Oral presentation: “High mobility in double gate quantum dot thin film field effect transistors”.

2010, November 14: – "Measuring dose fields over nuclear facilities: a comparison of alternative methods of delivery of radiometric equipment", Oral presentation at “Engineering of scintillation materials and radiation technology ISMART-2010”.